

# Readout studies with planar GEM

TEST BEAM results

SPS North Area H4 beam line

CERN PREVESSIN



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# Overview

The test is part of development of a Cylindrical GEM for KLOE-2. A prototype with 1D readout was realized and tested last year.

Final design includes 2-D readout (XV with 40° angle)

We need to fully characterize 2-D readout (charge sharing, grounding, crosstalk, magnetic field etc)

We built a planar triple GEM's telescope (10x10 cm<sup>2</sup>) tested at the H4 SPS beam line at CERN; all the GEM are double masked.

The test has been done in magnetic field with range 0T-1.3T

This study has been done in the framework of the R&D for KLOE-2 experiment

The project for KLOE-2 Inner Tracker has been approved by INFN

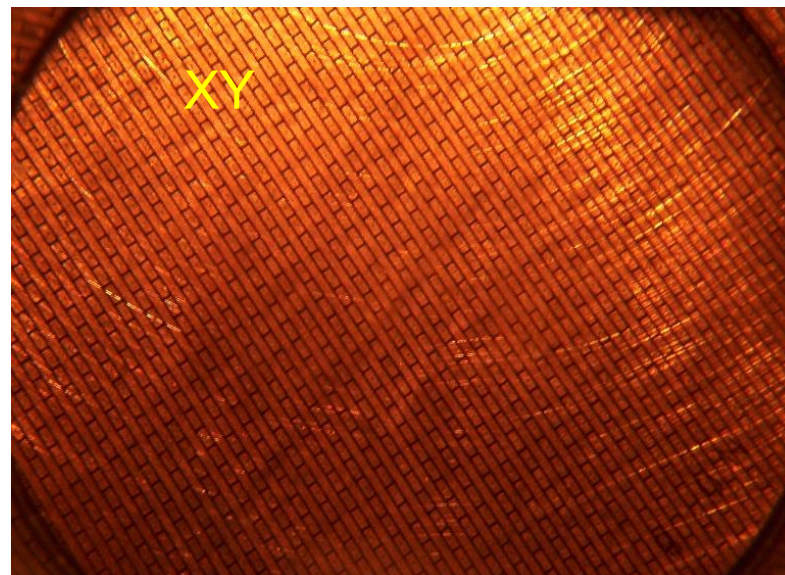
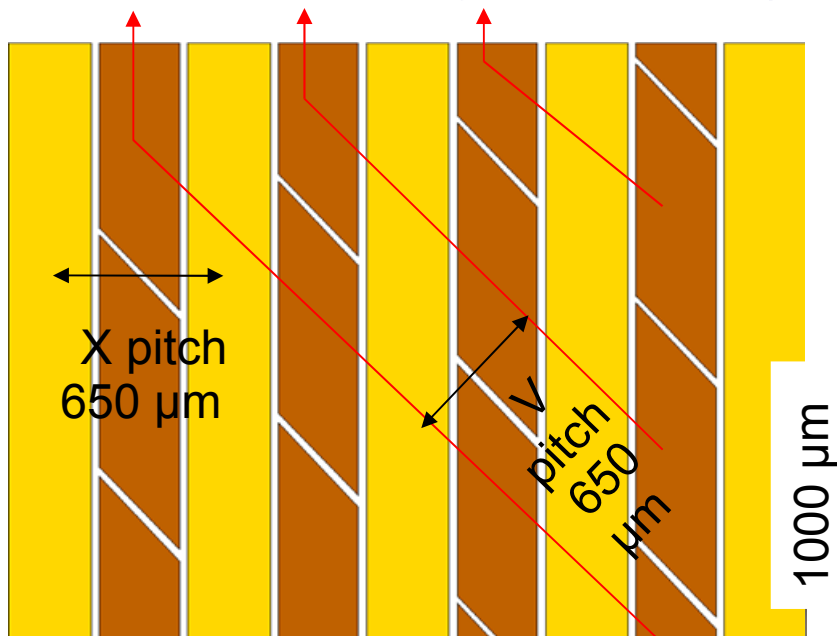
# Tracking telescope:

4 GEMs with XY (used as *external trackers*)

## Chamber under investigation:

1 GEM with XV readout strips (*the 2-D pattern we will use for the IT*)

650  $\mu\text{m}$  pitch, with digital readout (GASTONE: an ASIC chip realized for this project).

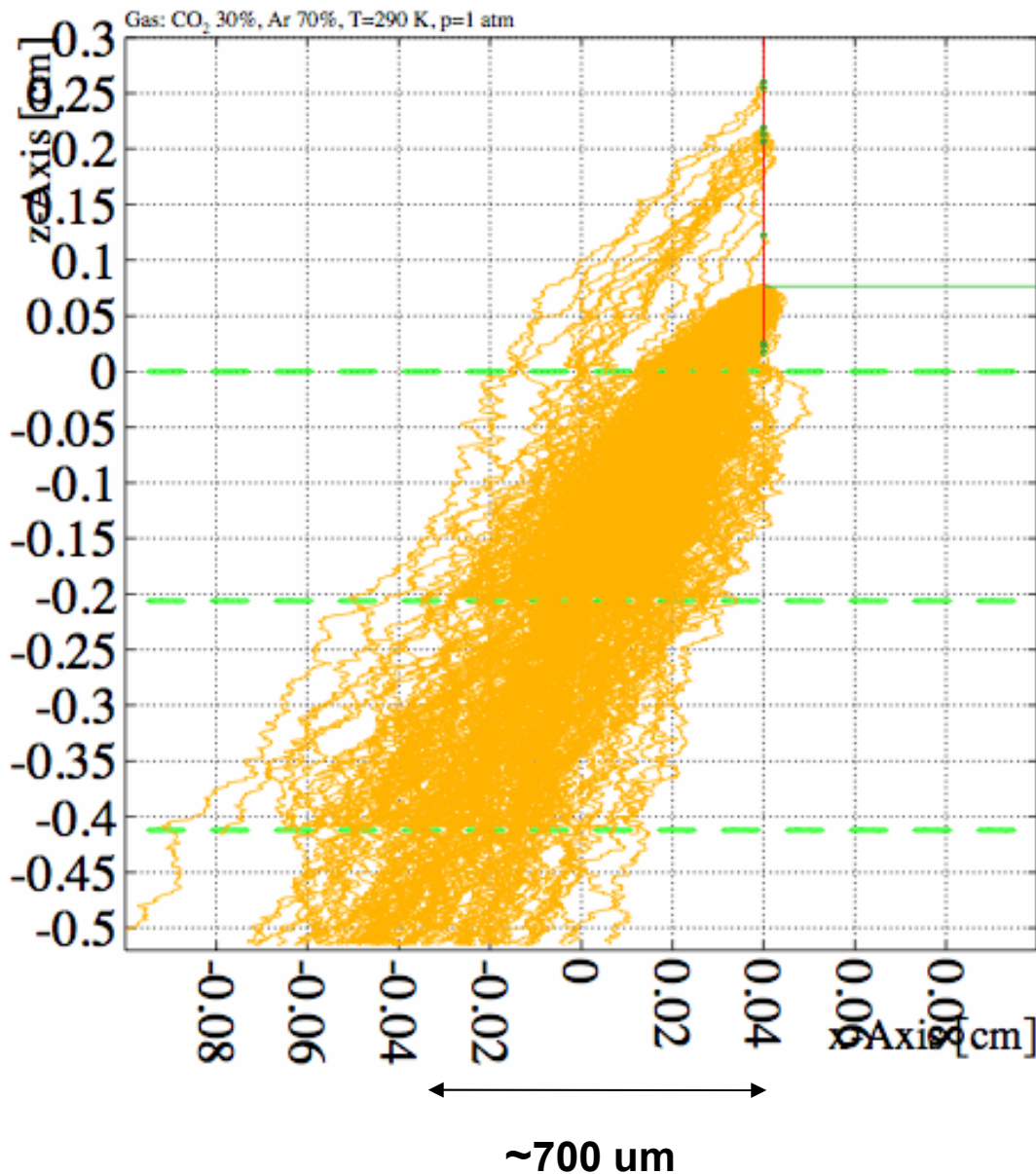




# Effect of magnetic field

At test beam we used Goliath magnet, B field up to 1.5 T  
The chambers were filled with **Ar/CO<sub>2</sub>**

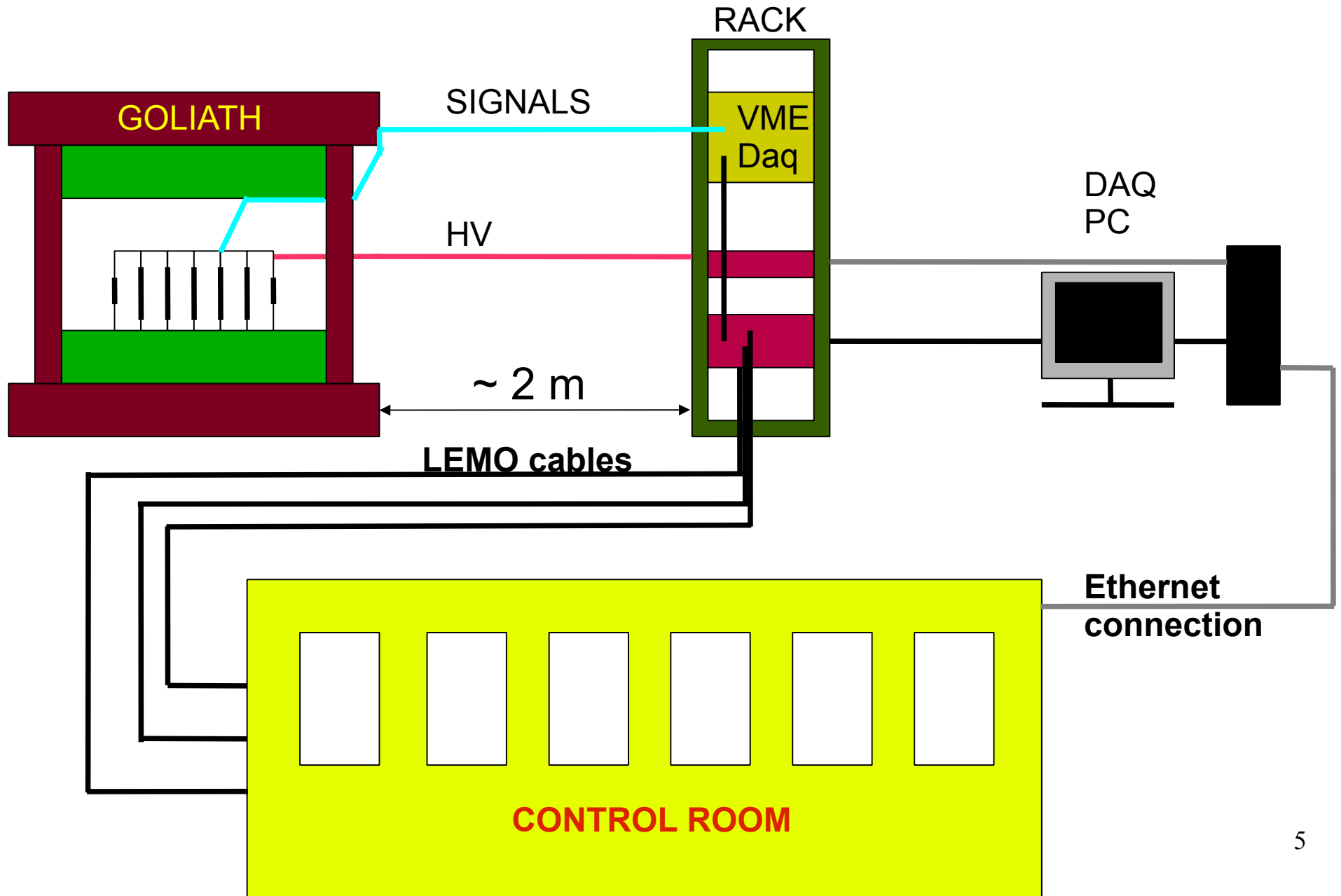
Layout of the cell

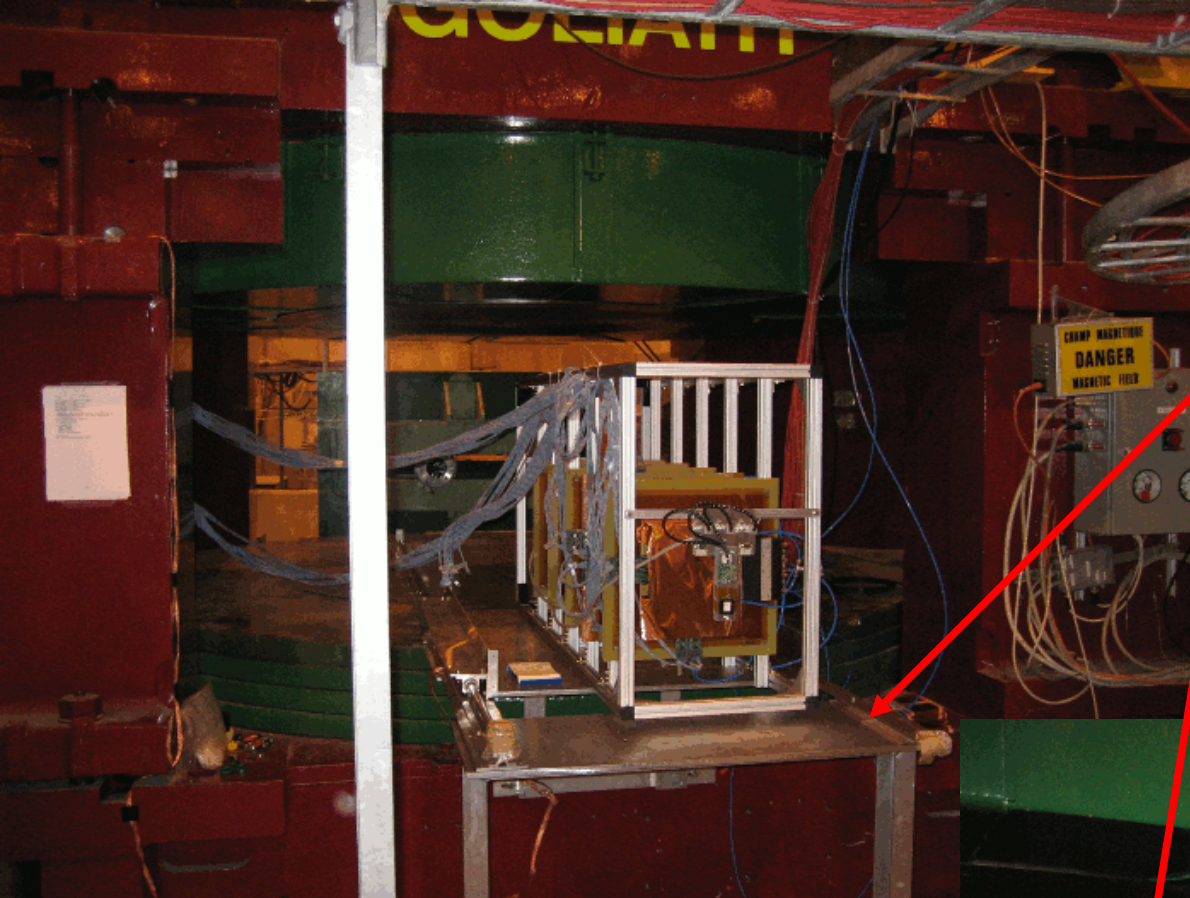


A triple GEM (3/2/2/1) was built with ANSYS and simulation of electrons drift motion with 0.5 T (the foreseen KLOE-2 magnetic field) was done with GARFIELD

Ar/CO<sub>2</sub>=70/30  
B=0.5 T  
Mean Lorentz angle ( $\langle\alpha_L\rangle$ )  $\sim 8^\circ$ - $9^\circ$

# The experimental layout





SPS North Area H4 beam:  
 $\pi$  150 GeV/c

Sliding table

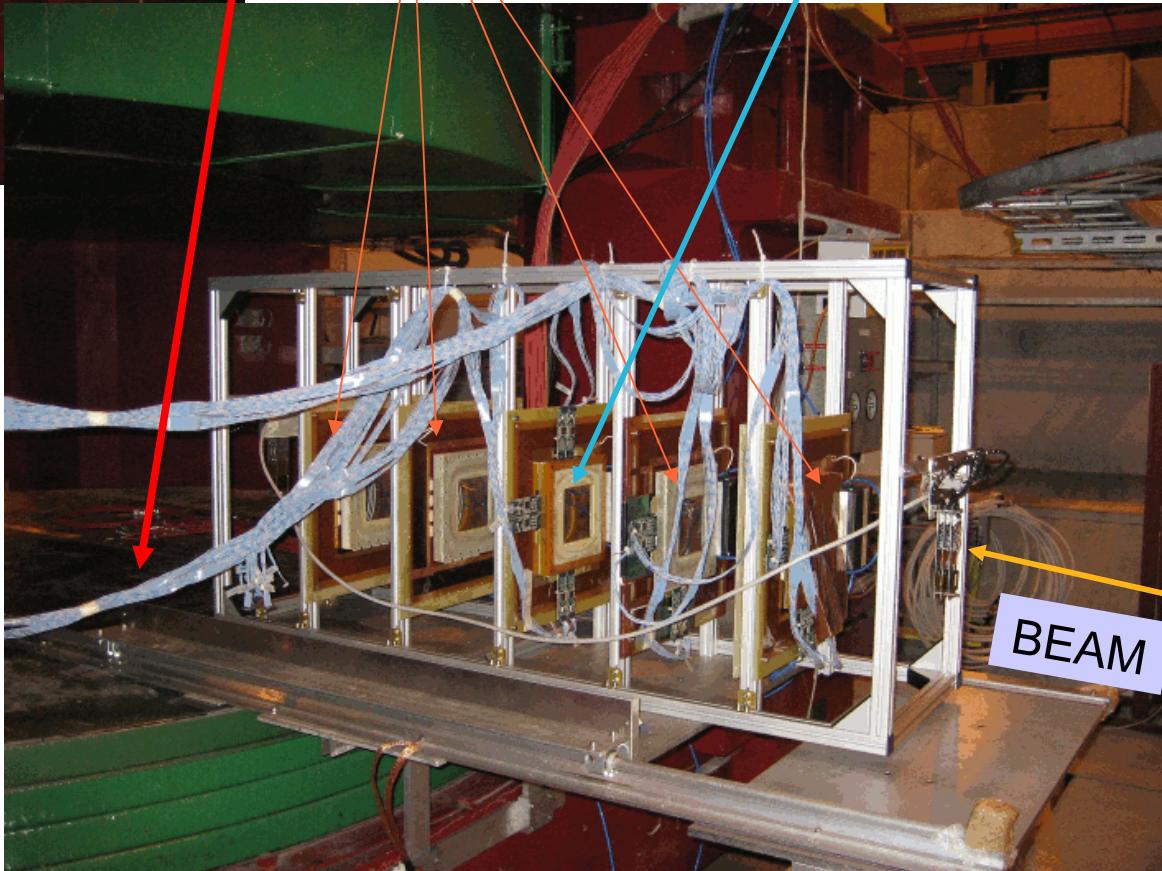
GEM with X - V readout

GEMs with X - Y readout

**Gas:** Ar-CO<sub>2</sub> 70-30  
**Fields:** 1.5 - 3.0 - 3.0 - 5.0 kV/cm  
**V<sub>GEM</sub>:** 390-380-370 = 1140V, gain~2·10<sup>4</sup>

**FEE:**  
GEMs partially equipped with 22  
GASTONE boards

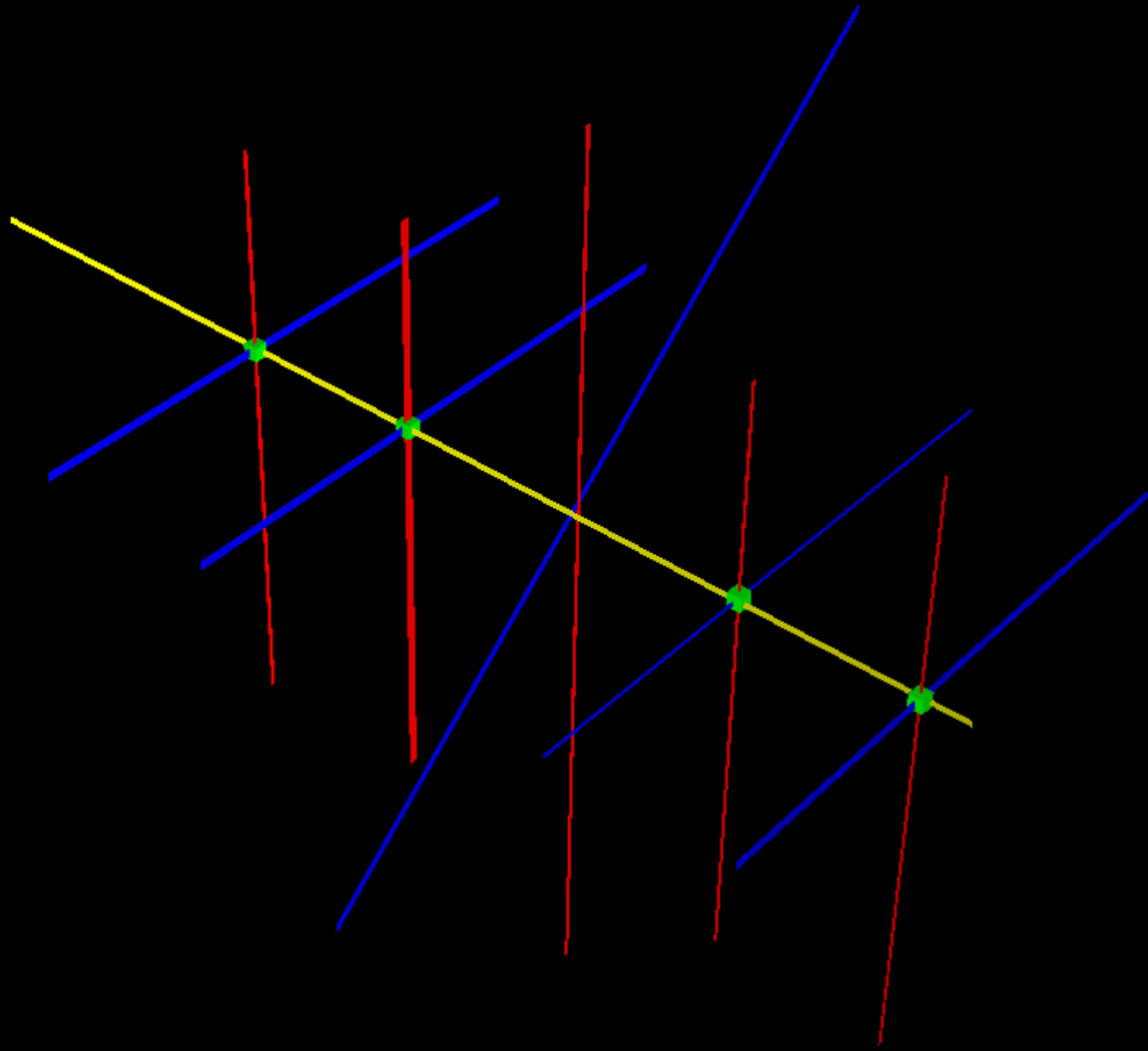
**trigger:**  
6 scintillators with SiPM



BEAM







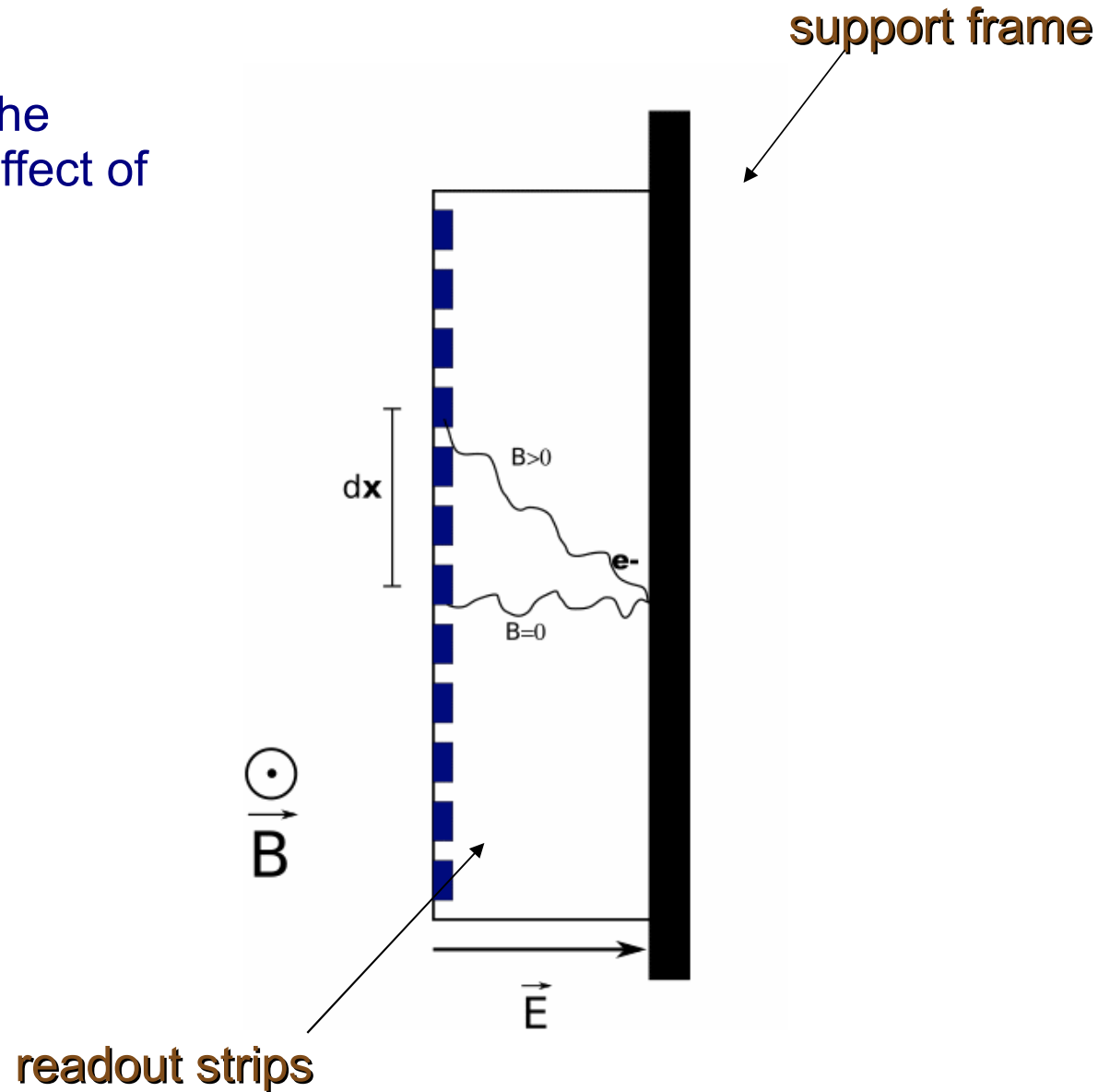


# What we measured

- The displacement of electrons due to the Lorentz strength
- The spatial resolution depending on magnetic field
- Reconstruction efficiency and cluster size in function of  $\Delta V$  and B

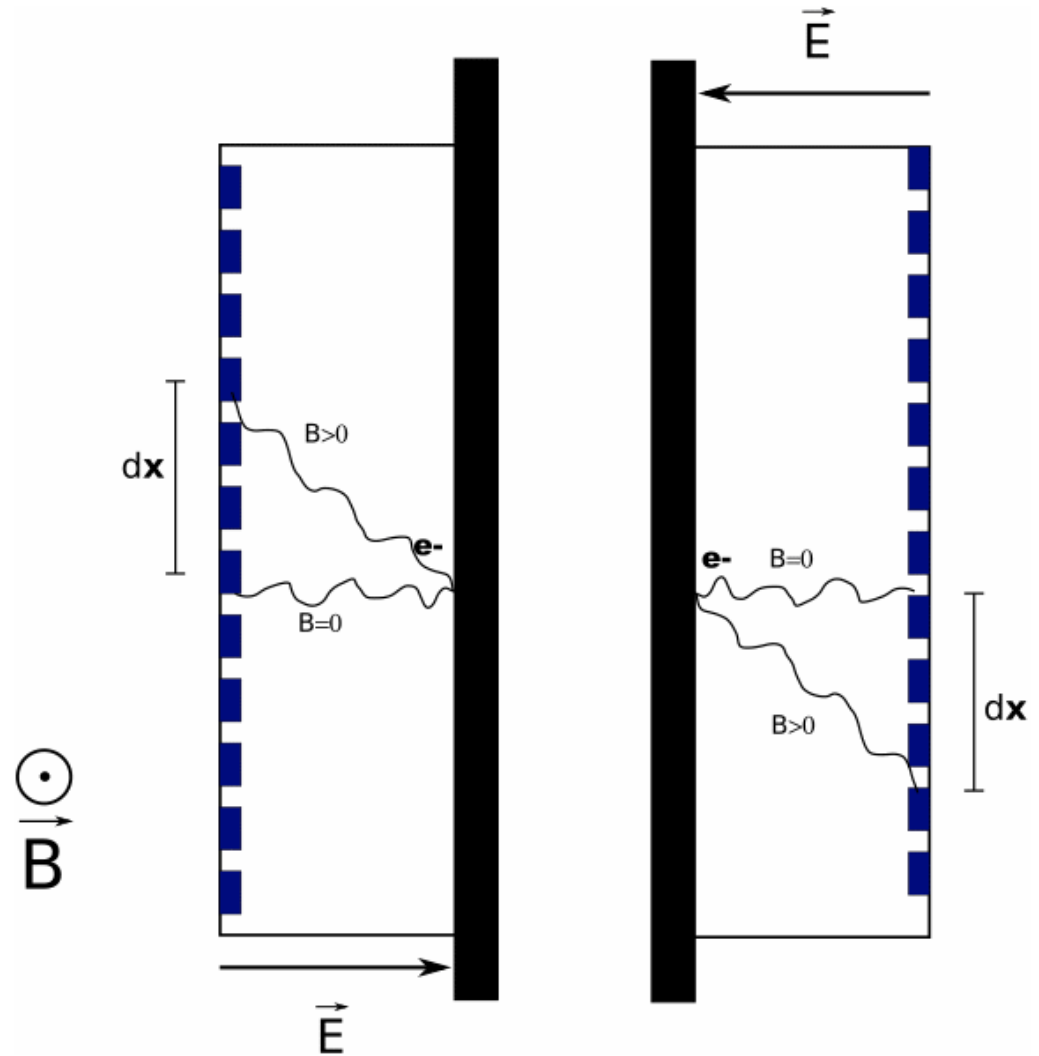
# Lorentz angle

- $dx$  - displacement on the readout plane due to effect of the magnetic field

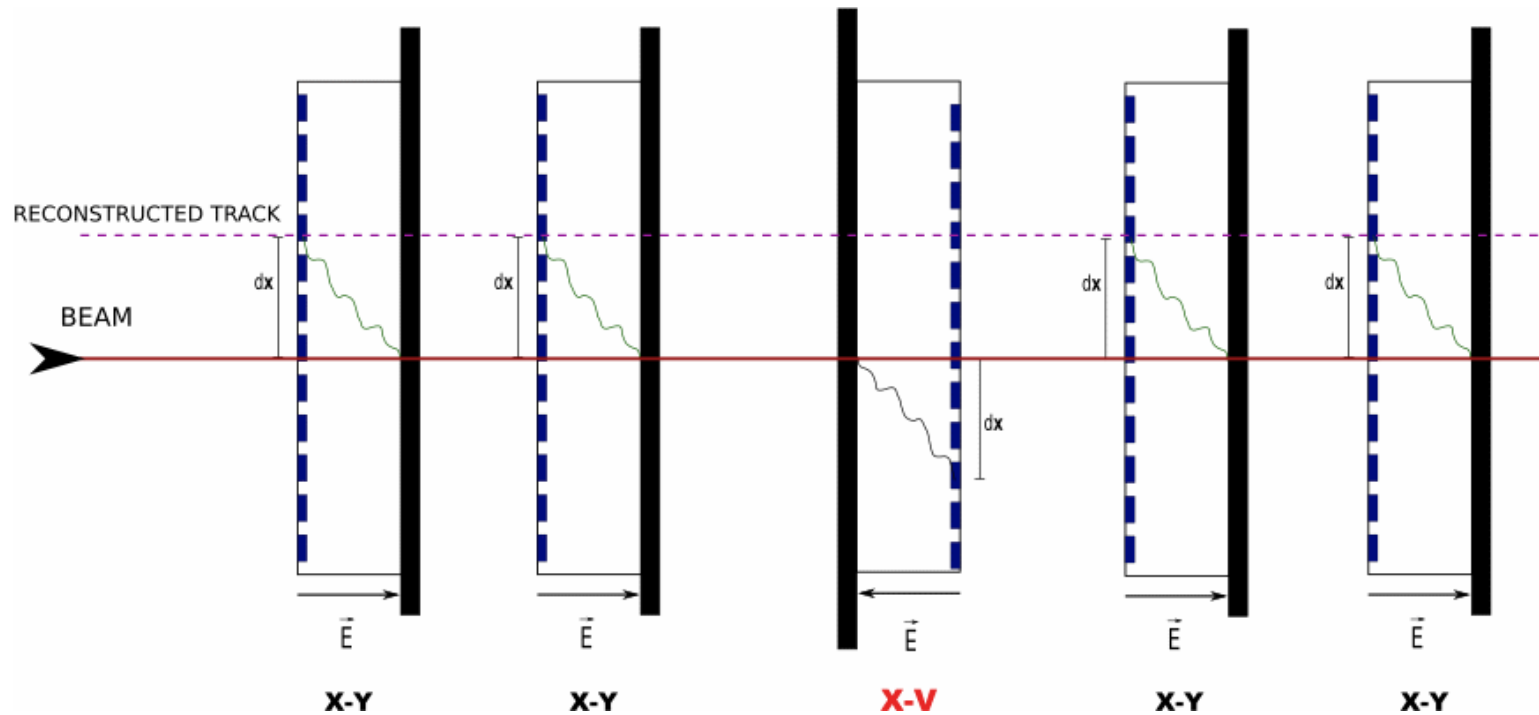


# Lorentz angle

- $dx$  - displacement on the readout plane due to effect of the magnetic field
- after rotation the electric field changes direction and the displacement will be reversed



# Lorentz angle



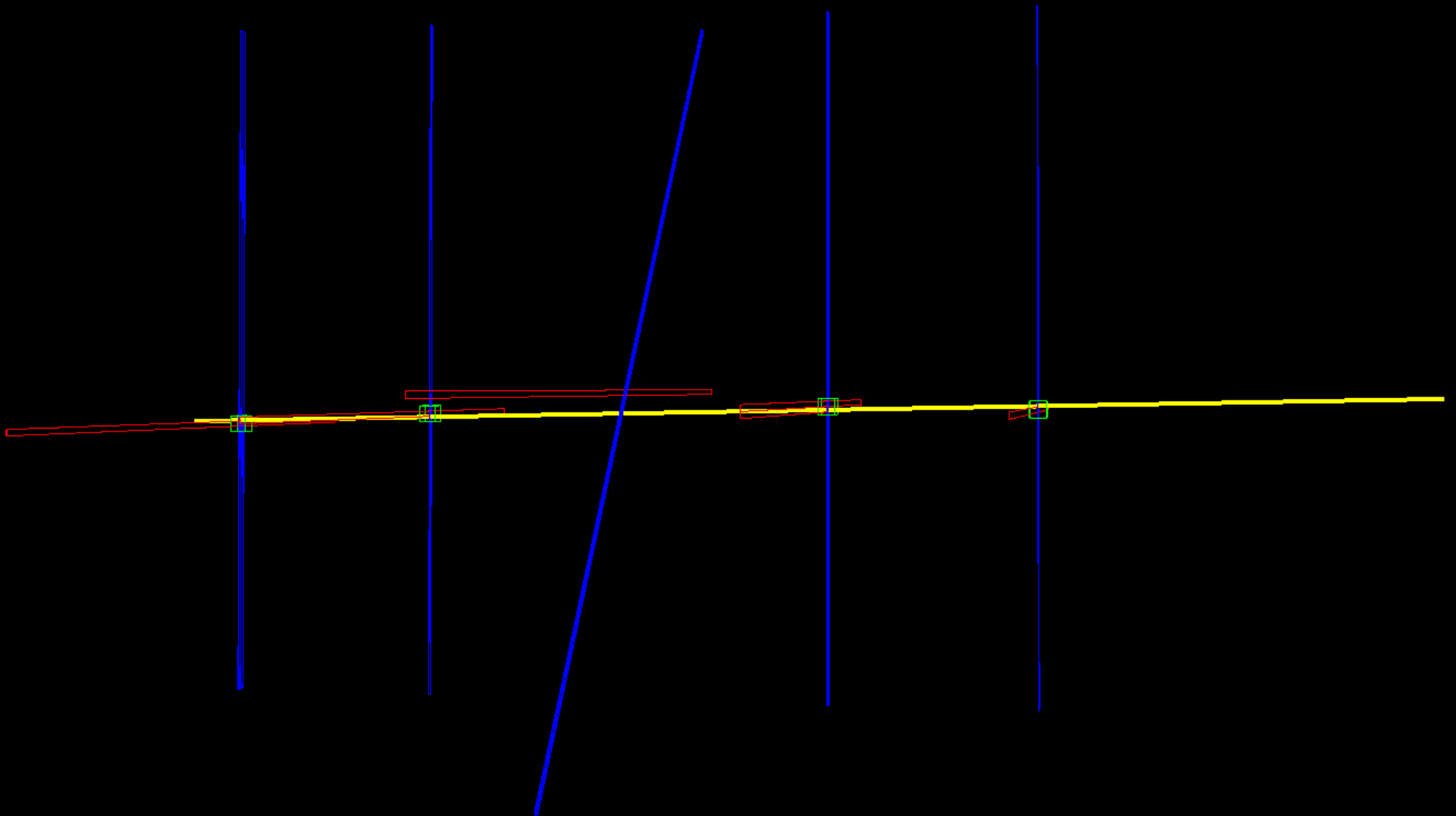
- we align the setup with  $B = 0$
- turn on B field
- we reconstruct the track using only 4 X-Y planes
- we measure the displacement on X-V plane

measured displacement  $D = 2 \cdot r \cdot \tan \alpha_L$

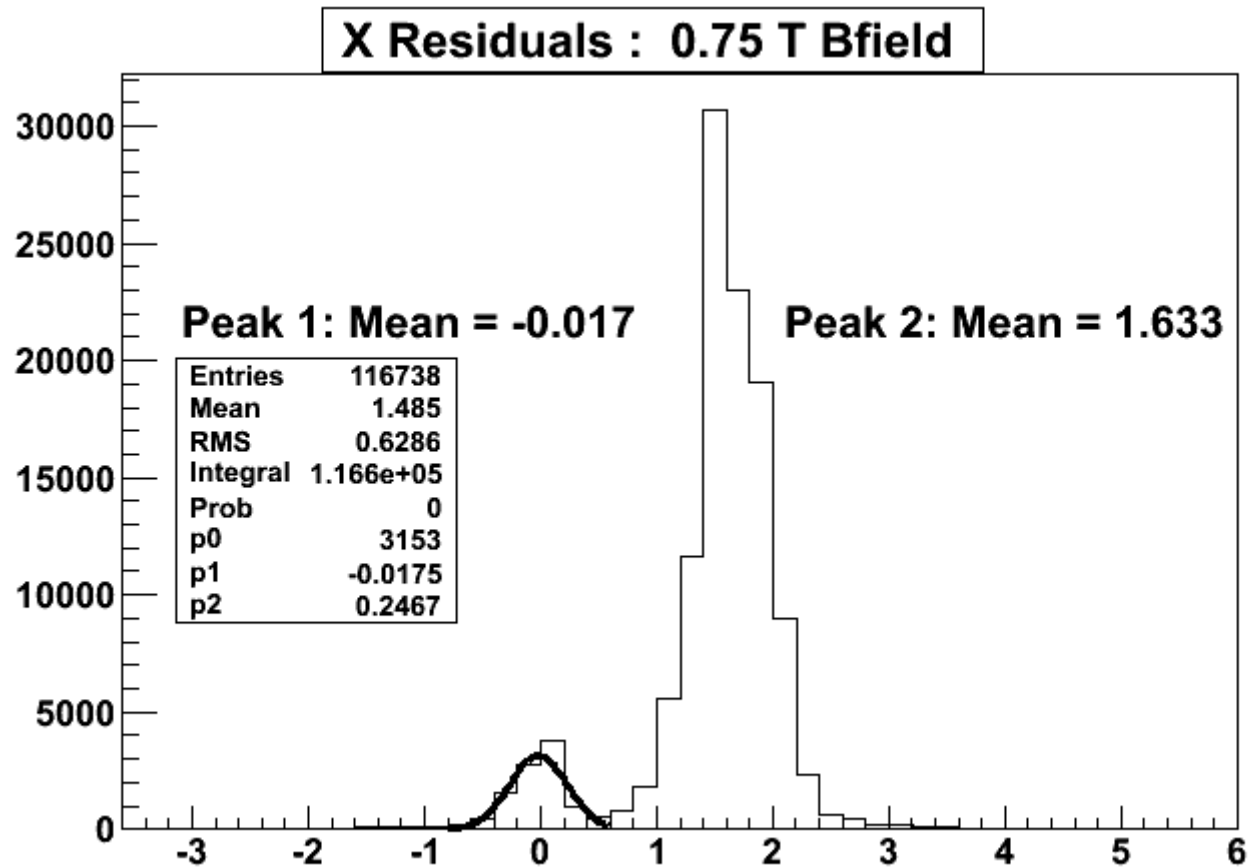
(where  $r$  is effective thickness of the detector)



# Lorentz angle



# Displacement



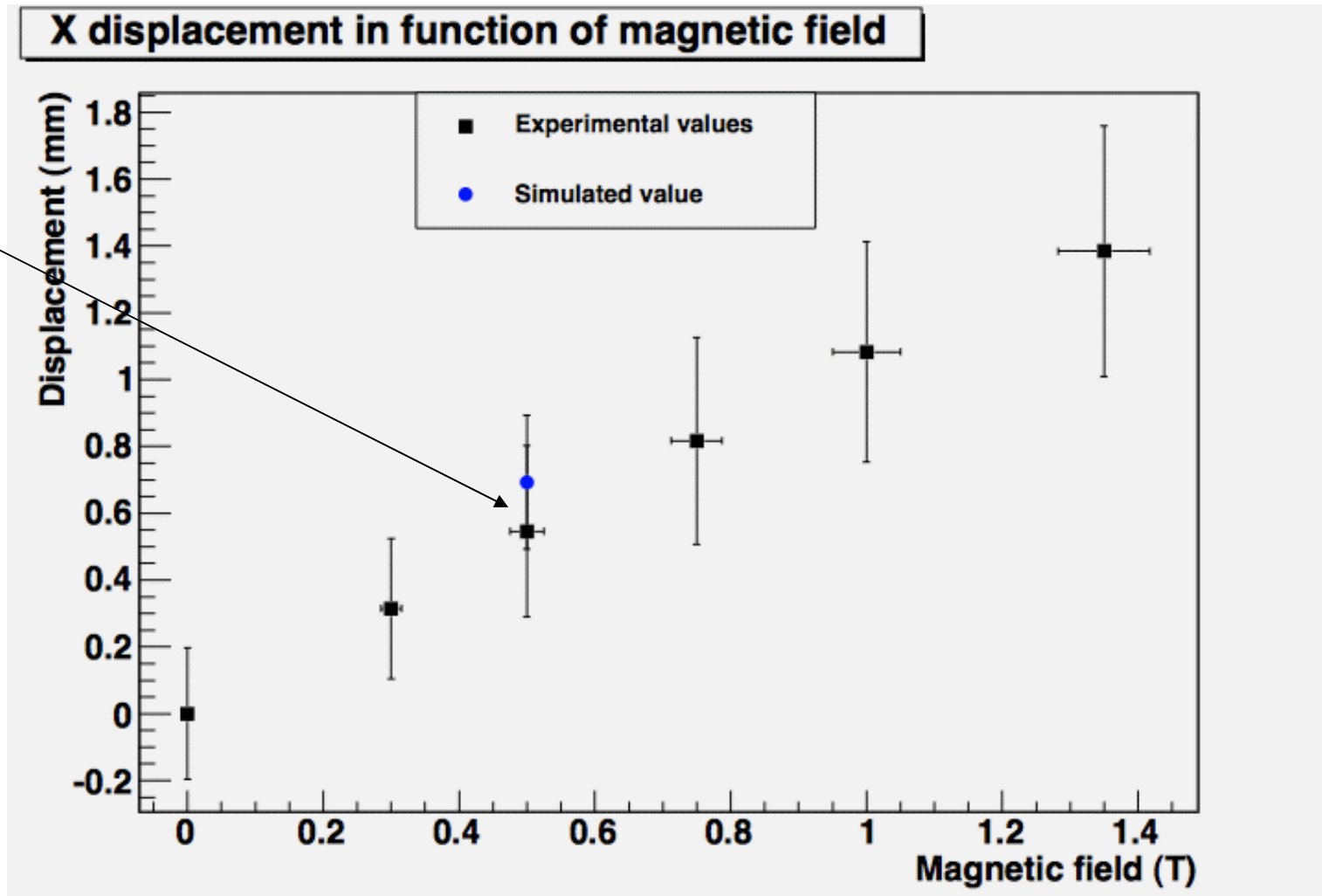
**THE MAGNET ACCIDENTALLY  
TRIPPED  
DURING THE RUN**

# Lorentz angle measurement

Blue point from very preliminary GARFIELD simulation

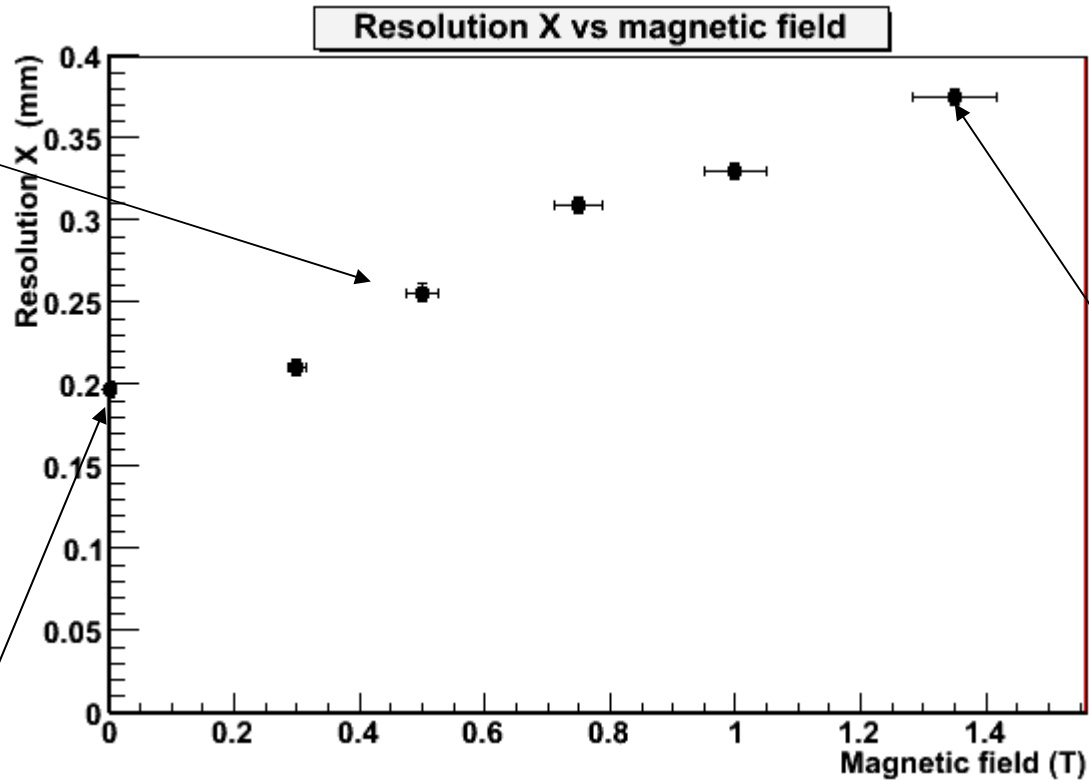
The point fits roughly calculated (factor 0.5 included) measured offset at 0.5 T

KLOE  
B field



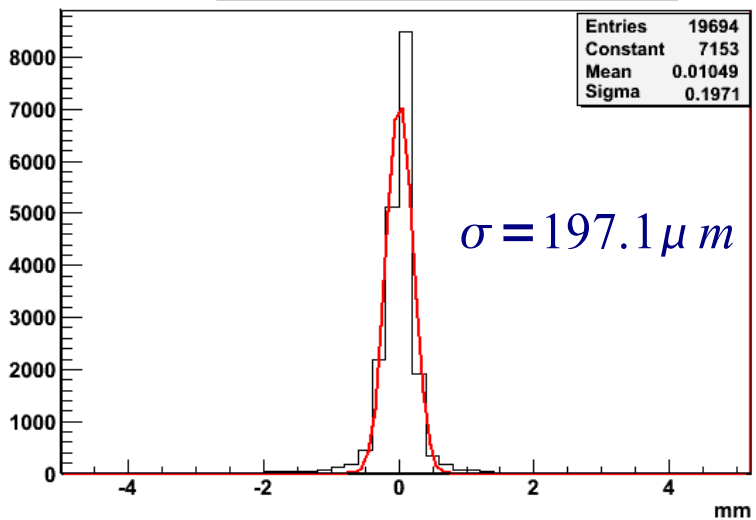
# Resolution in X plane (bending plane)

KLOE B  
field



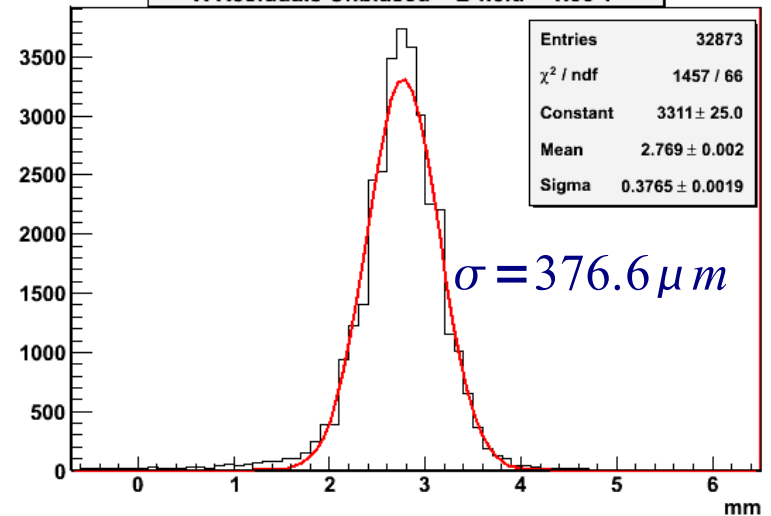
$V_{\text{GEM}}$ : 390-380-370  
=1140V, gain $\sim 2 \cdot 10^4$

X Residuals Unbiased B field = 0T



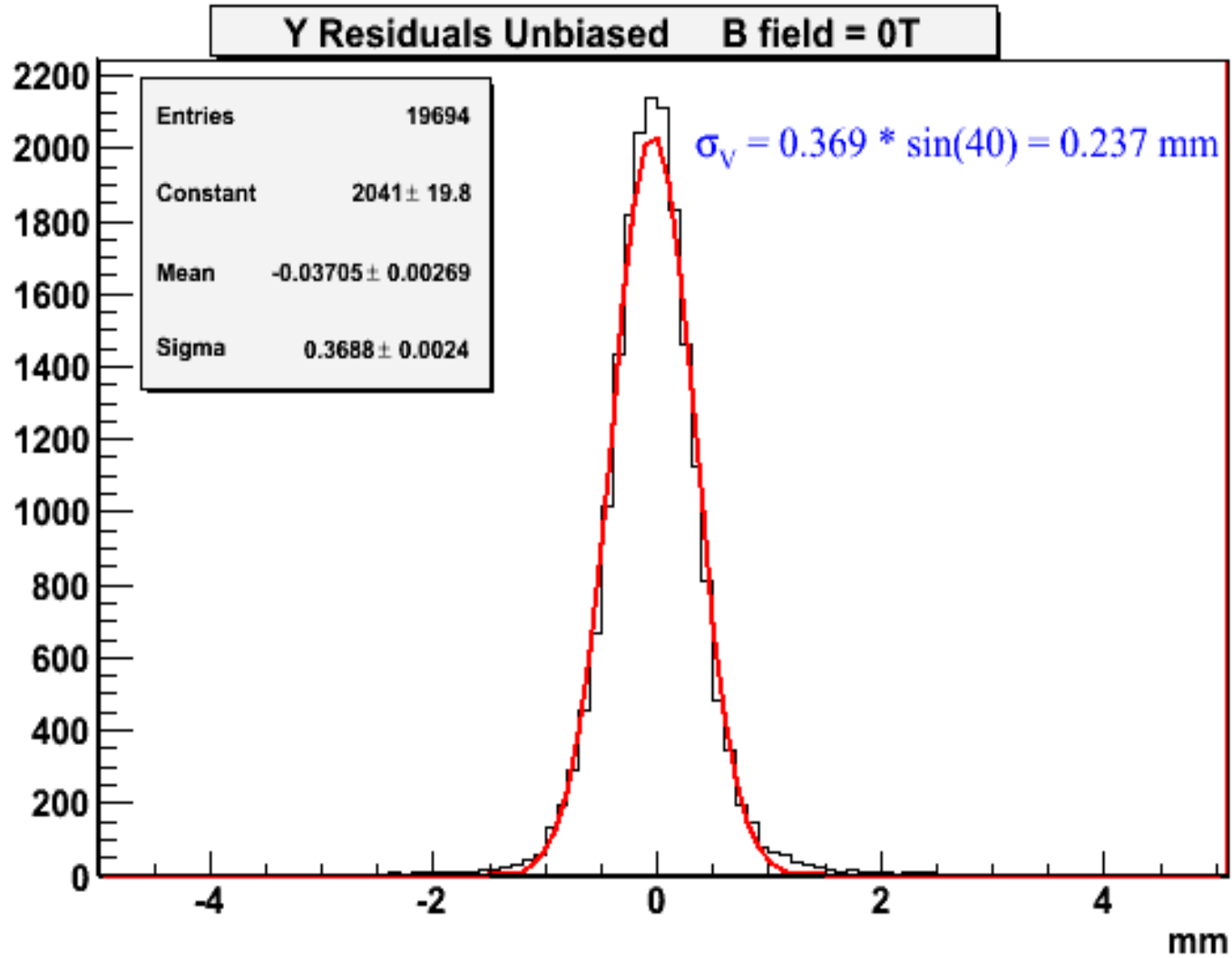
The magnetic  
field increases  
the spread of the  
electrons

X Residuals Unbiased B field = 1.35 T





# Y resolution

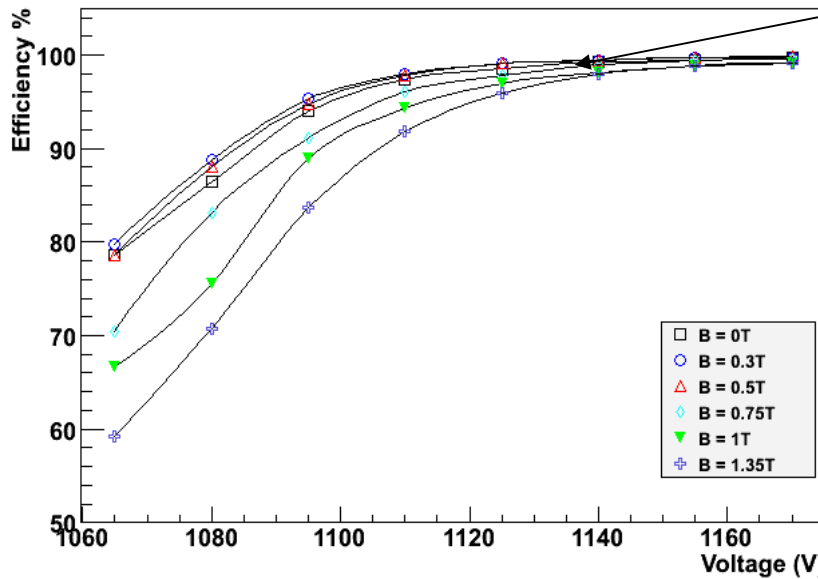


40° is the angle between the V strips and the y coordinate

# Efficiency measurements

No significant variations among the curves of 0T, 0.3T and 0.5T

Efficiency vs Voltage (th=3.5 fC)

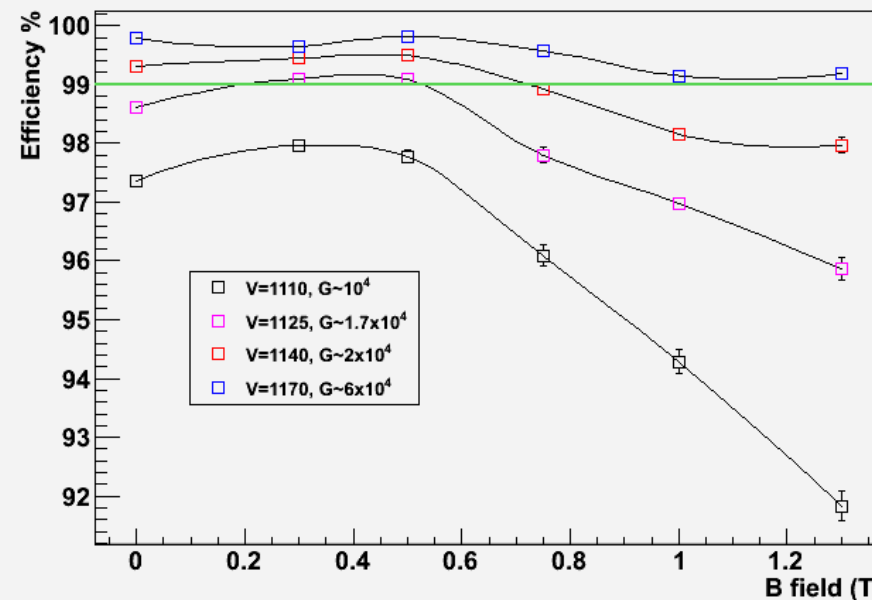


Working point:  $G \sim 2 \cdot 10^4$

In the electron drift motion the diffusion adds to Lorentz strength, increasing their spread. The bending plane is the x-z: for this reasons the effect is greater for x strips than for the v ones.

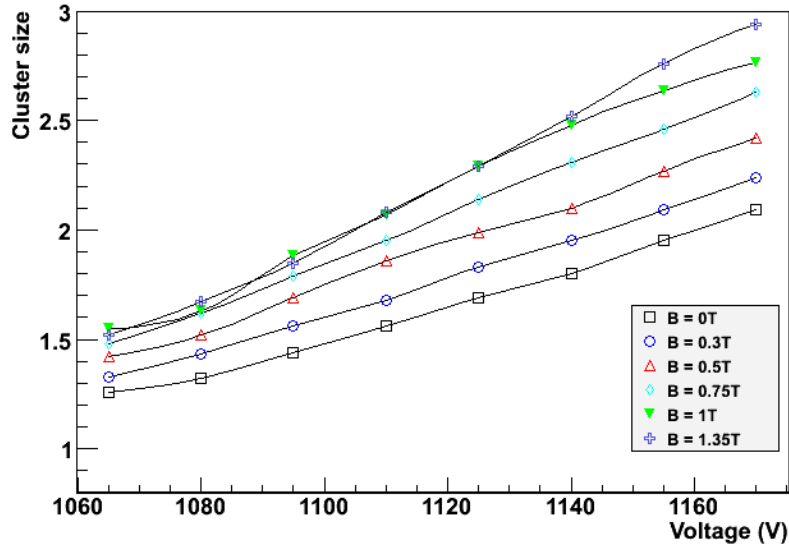
A good efficiency in presence of magnetic field can be reached working at higher gain

Efficiency vs B field

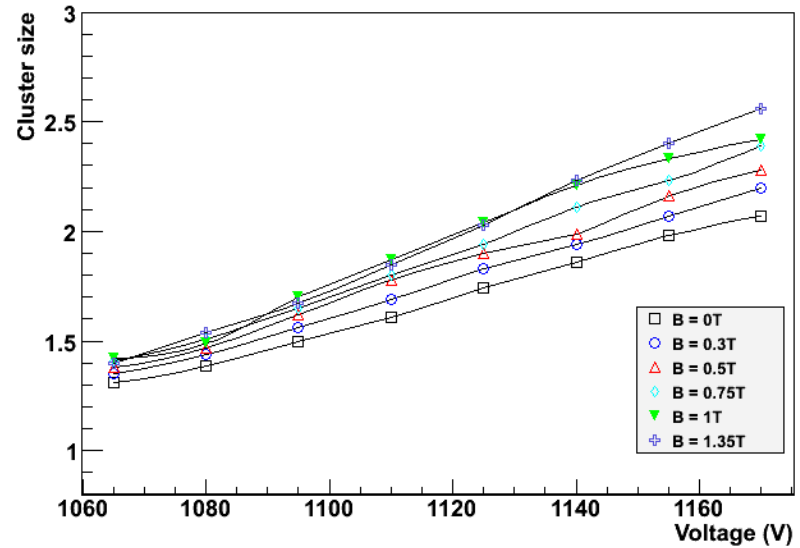


# Cluster size measurements

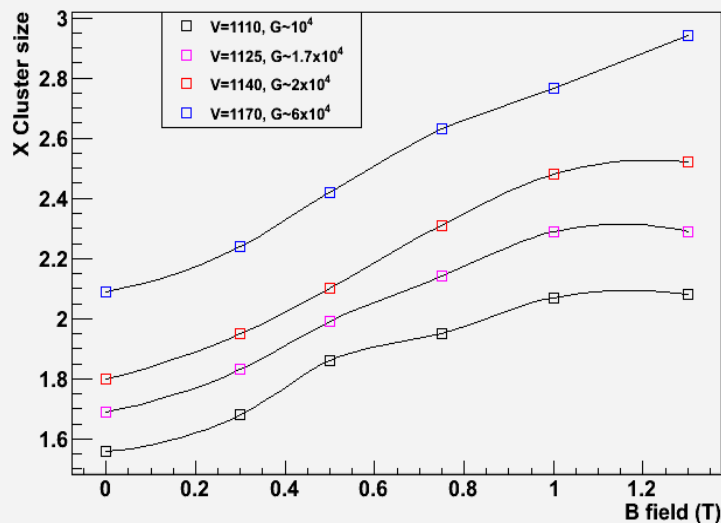
X Cluster size vs Voltage (th=3.5 fC)



V Cluster size vs Voltage (th=3.5 fC)



Cluster size vs B field



The cluster size gets worse as magnetic field increases because of a larger spread of electrons in the gas gaps

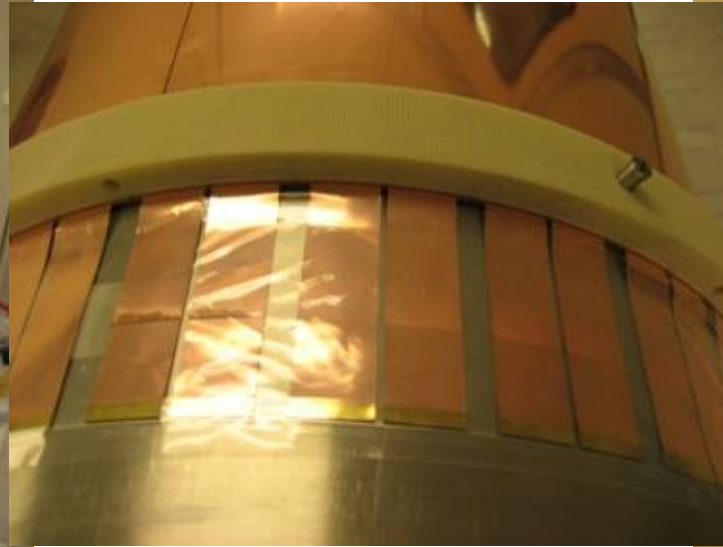
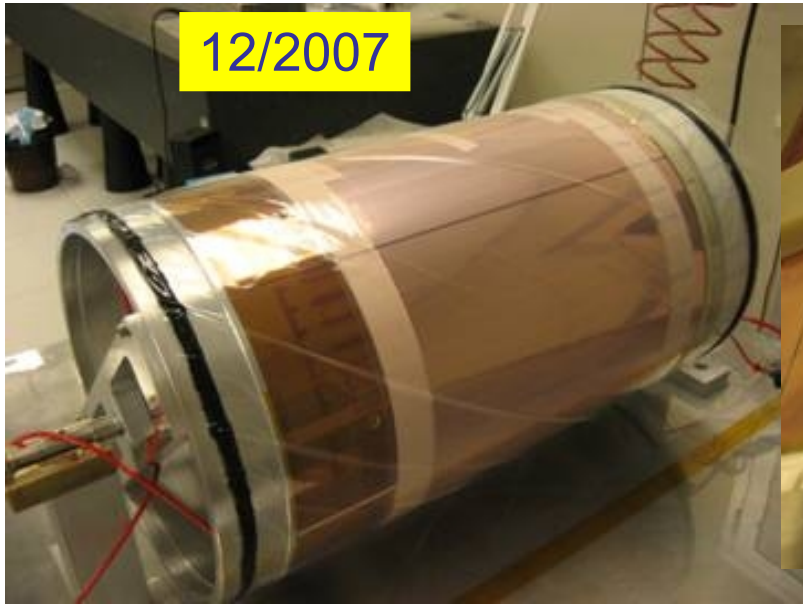
# Conclusions

- The XV readout system for the IT with CGEM of KLOE-2 experiment works as expected
- Magnetic field up to 0.5 T doesn't significantly affect reconstruction efficiency and the spatial resolution of the detector
- Simulation studies are in progress



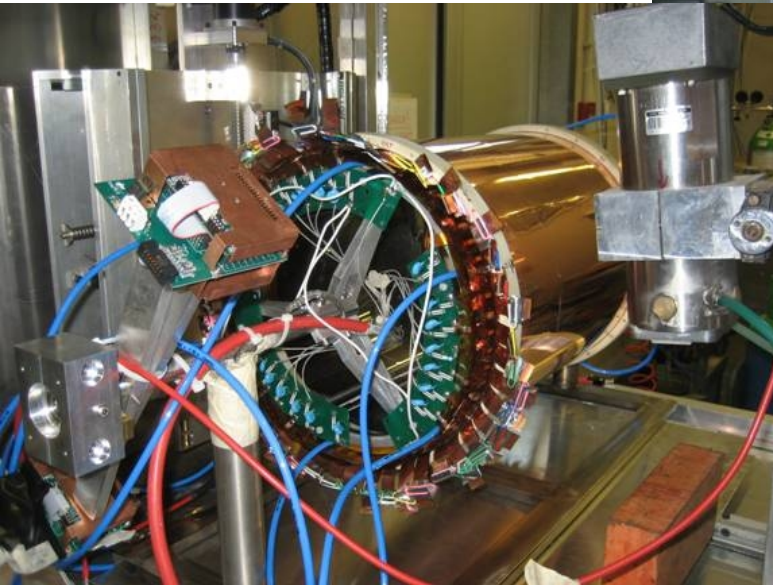
# Construction of the CGEM proto & test

12/2007

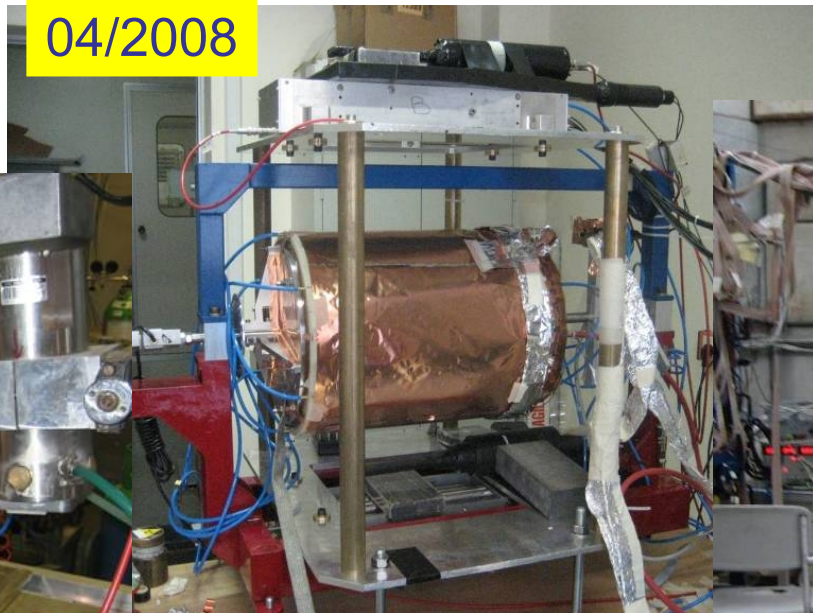


07/2008

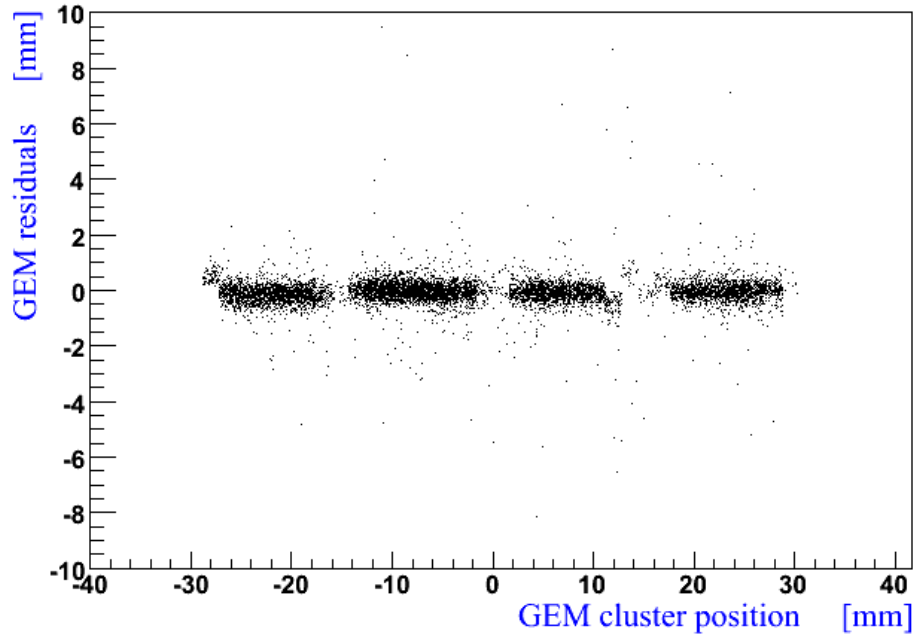
02/2008



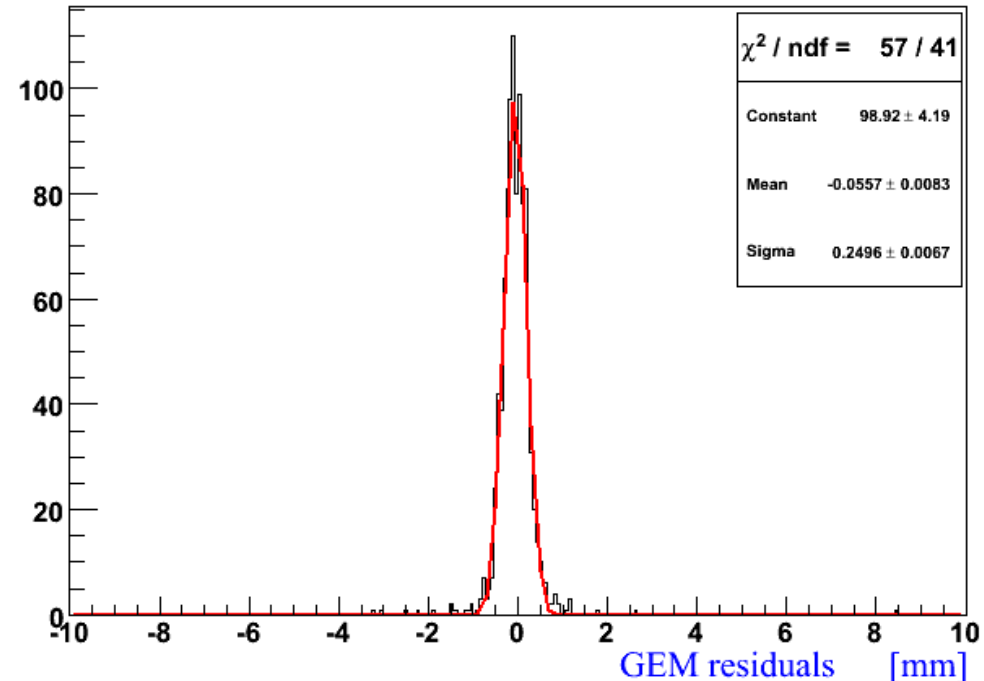
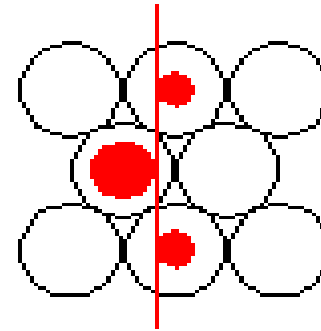
04/2008



# CGEM TB-2008 results: 1-D strips (650 $\mu\text{m}$ pitch)



GEM residuals with respect to the track reconstructed by the external drift tubes



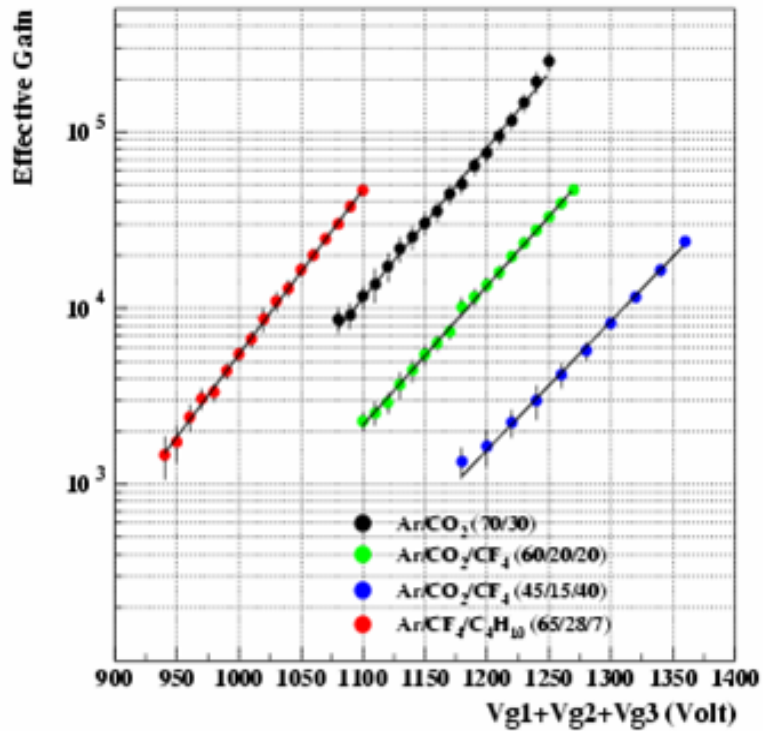
$$\sigma_{\text{global}}^2 = \sigma_{\text{GEM}}^2 + \sigma_{\text{tracker}}^2$$

$$\sigma_{\text{GEM}} = \sqrt{(250 \mu\text{m})^2 - (140 \mu\text{m})^2} \simeq 200 \mu\text{m}$$

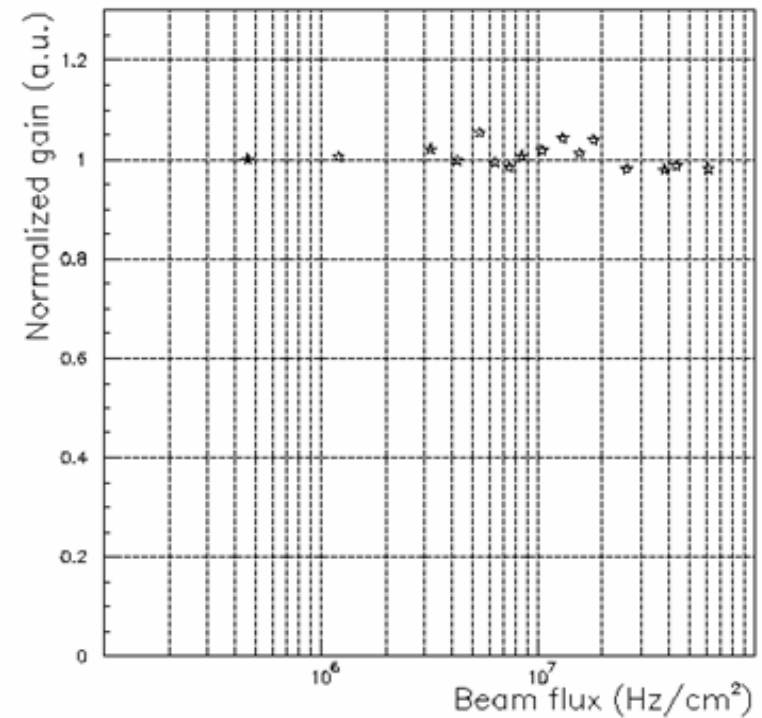
compatible with  $\langle \text{pitch} \rangle / \sqrt{12}$   
(with digital readout)

# Operation of a GEM detector

## Gas Gain



## Rate Capability





# GASTONE (Gem Amplifier Shaper Tracking ON Events) ASIC

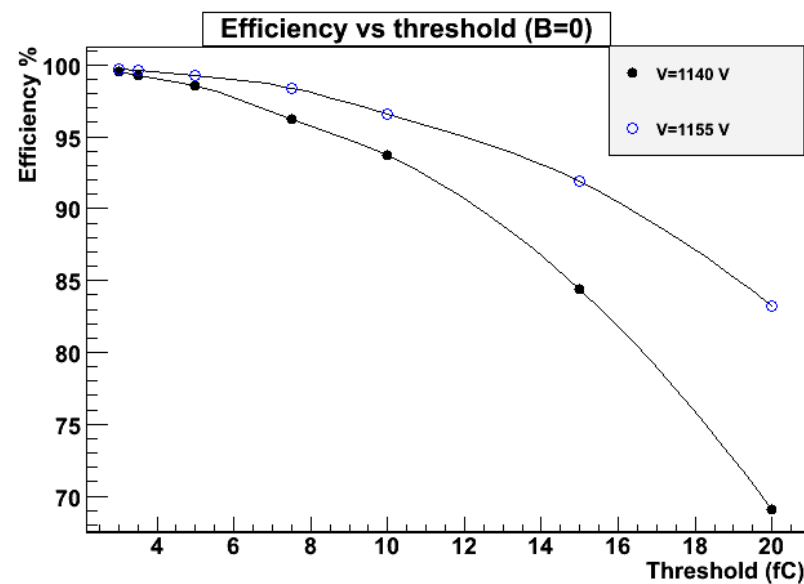
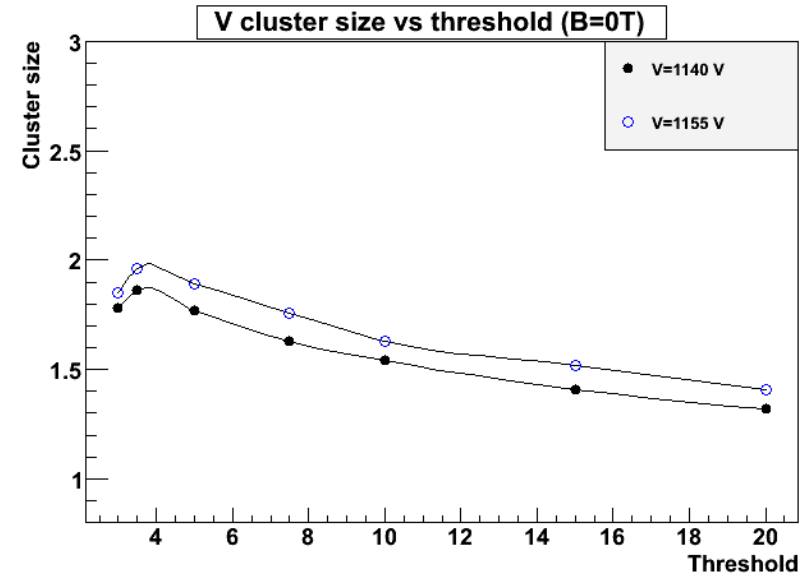
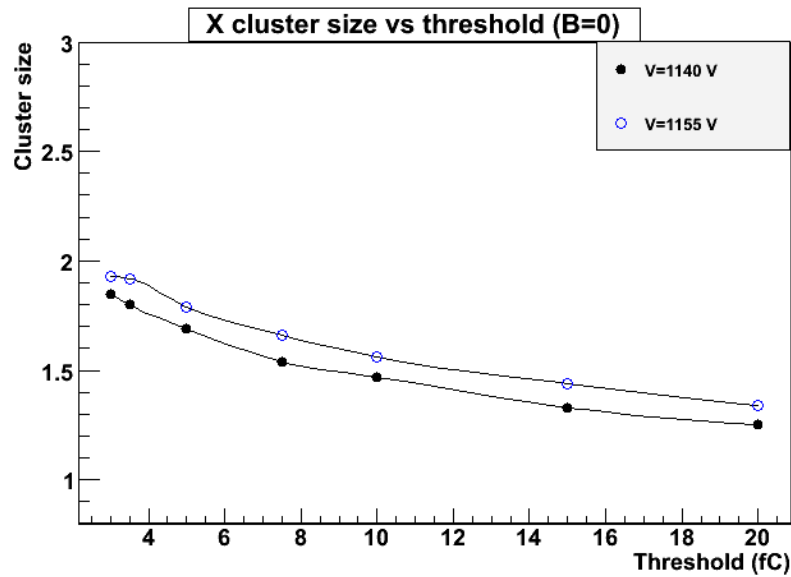


	GASTONE	
Sensitivity (pF)	20 mV/fC	
$Z_{IN}$	400 $\Omega$ (low frequency)	
$C_{DET}$	1 – 50 pF	
Peaking time	90 – 200 ns (1 – 50 pF)	
Noise (erms)	974 e <sup>-</sup> + 59 e <sup>-</sup> /pF	
Baseline restorer	yes*	
Channels/chip	64*	
Readout	LVDS/Serial	
Power consum.	≈ 0.6 mA/ch	

- Low power consumption and high integration chip needed to satisfy IT requirements
- Time and noise characteristics to be adapted to large spread of  $C_{DET}$  due to XV readout
- 4 different blocks:
  - charge sensitive preamplifier
  - shaper
  - leading-edge discriminator (with programmable thr.)
  - monostable to stretch the digital signal, waiting for L1 trigger
- 16 channel release with protection network inside the chip and BLR already tested
- 64 channels release for the end of 2008



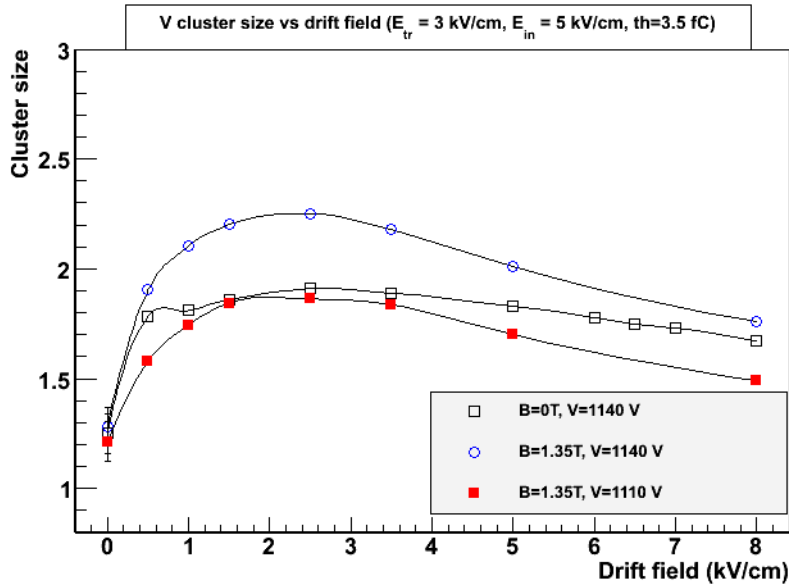
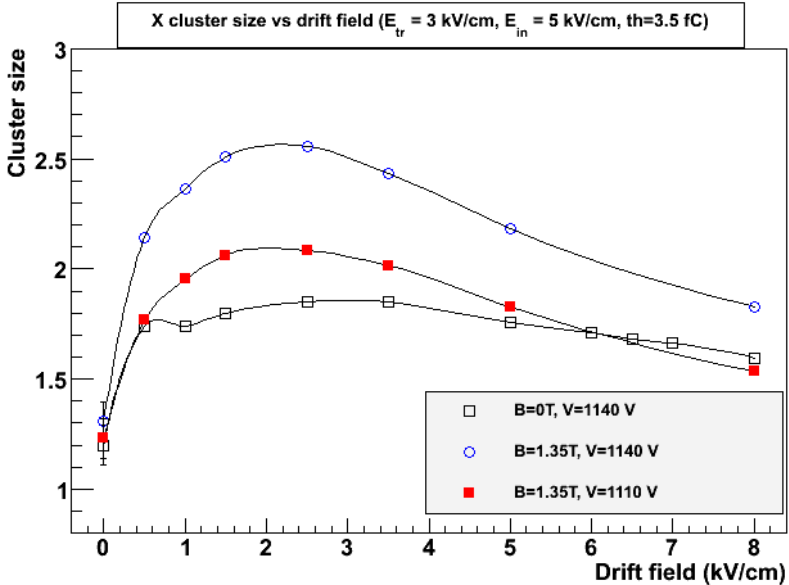
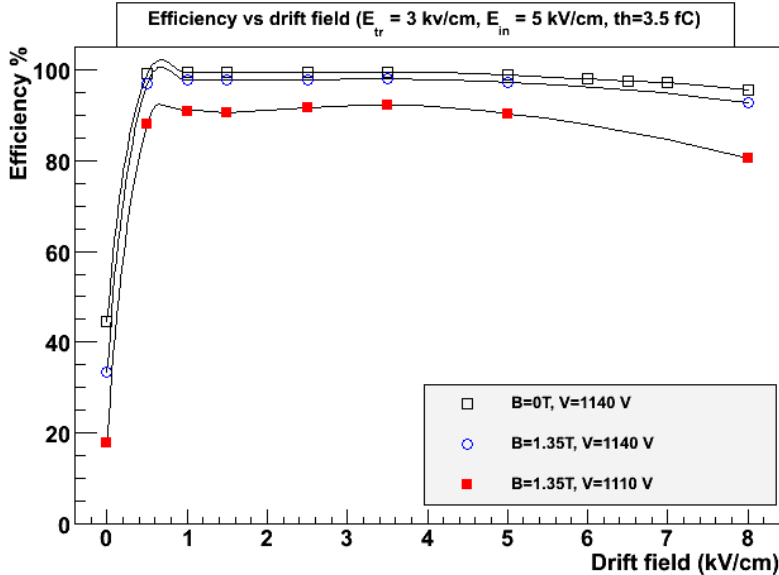
# Threshold scan on GASTONE chip



GASTONE charge  
sensitivity = 25 mV/fC

Reference  
threshold = 3.5 fC

# Drift field scan



# Transfer field scan

